## **STARPOWER**

#### **SEMICONDUCTOR**

## **Rectifier Diode**

### RD150FPS180K7S

1800V/150A in one-package

#### **General Description**

STARPOWER Rectifier Diode Power Module provides ultra low conduction loss. They are designed for the applications such as SMPS.

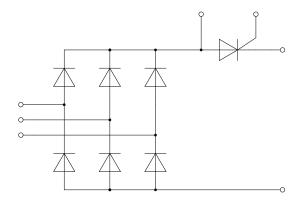
#### **Features**

- Low forward voltage drop
- Small temperature coefficient
- High Surge Capacity
- Low inductance
- Isolated Copper Baseplate Using DBC Technology

#### **Typical Applications**

- Input bridge rectifier
- AC/DC motor control
- Power supply

#### **Equivalent Circuit Schematic**





## Absolute Maximum Ratings $T_c$ =25°C unless otherwise noted

#### **Rectifier Diode**

Symbol	Description	Value	Unit
$V_{RRM}$	Repetitive Peak Reverse Voltage	1800	V
V <sub>RSM</sub>	Non-repetitive Peak Reverse Voltage	1900	V
$I_{\rm F}$	Forward Current T <sub>C</sub> =100°C	150	A
I <sub>FSM</sub>	Surge Forward Current V <sub>R</sub> =0V,t <sub>p</sub> =10ms,T <sub>i</sub> =45°C	1800	Α
	$V_R = 0V_{,t_p} = 8.3 \text{ms}, T_i = 45^{\circ} \text{C}$	1850	Α
$I^2t$	$I^2$ t-value $V_R=0V_{t_p}=10$ ms, $T_i=45$ °C	16200	$A^2s$
	$V_{\rm R} = 0V_{\rm t_{\rm R}} = 8.3 \rm ms, T = 45^{\circ} C$	14260	AS

## **Thyristor**

Symbol	Description	Value	Unit	
$V_{RRM}$	Repetitive Peak Reverse Voltage	1800	V	
$V_{RSM}$	Non-repetitive Peak Reverse Voltage	1900	V	
$I_{\mathrm{T}}$	On-state Current T <sub>C</sub> =100°C	150	A	
ī	Surge Forward Current V <sub>R</sub> =0V,t <sub>p</sub> =10ms,T <sub>j</sub> =45°C	2400	Δ.	
$I_{TSM}$	$V_R = 0V_{,t_p} = 8.3 \text{ms}, T_j = 45^{\circ}\text{C}$	2550	Α	
$I^2$ t	$I^2$ t-value $V_R=0V$ , $t_p=10$ ms, $T_j=45$ °C	28800	$A^2s$	
1 t	$V_R = 0V_{t_p} = 8.3 \text{ms}, T_j = 45^{\circ} \text{C}$	27090	AS	
(di/dt)or	Critical Rate of Rise of On-state Current	150	A/μs	
(di/dt)cr	$f=50hz,I_G=0.45A,di_G/dt=0.45A/\mu s,T_j=150^{\circ}C$	130	A/μS	
(dv/dt)cr	Critical Rate of Rise of On-State Voltage	1000	V/µs	
	$V_{\rm D} = 0.67 V_{\rm DRM}, T_{\rm i} = 150^{\rm o} {\rm C}$	1000	V/μS	

#### Module

Symbol	Description	Value	Unit
T <sub>imax</sub>	Maximum Junction Temperature	150	°C
T <sub>jop</sub>	Operating Junction Temperature	-40 to +150	°C
$T_{STG}$	Storage Temperature Range	-40 to +125	°C
$V_{\rm ISO}$	Isolation Voltage RMS,f=50Hz,t=1min	4000	V

### **Rectifier Diode** T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
V	Diode Forward	I <sub>F</sub> =150A	$T_j=25^{\circ}C$			1.20	17
$V_{\rm F}$	Voltage	1 <sub>F</sub> -130A	$T_{j}=150^{\circ}C$			1.12	·
$V_{(TO)}$	Threshold Voltage	$T_{i}=150^{\circ}C$				0.86	V
*	Forward Slope	$T_{i}=150^{\circ}C$				1.7	mΩ
$r_{\mathrm{T}}$	Resistance	1 <sub>j</sub> -130 C				1./	1112.2
ī	Diode Reverse	$V_R = V_{RRM}$	$T_j=25^{\circ}C$			0.1	m A
$I_R$	Current	V <sub>R</sub> -V <sub>RRM</sub>	$T_{j}=150^{\circ}C$			2.0	mA

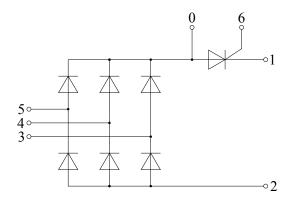
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Symbol	Parameter	<b>Test Conditions</b>		Min.	Тур.	Max.	Unit
$V_{\mathrm{T}}$	Forward Voltage	I <sub>T</sub> =300A	$T_j=25^{\circ}C$ $T_i=150^{\circ}C$			1.33 1.34	V
$V_{(TO)}$	Threshold Voltage	T <sub>i</sub> =150°C	11 130 0			0.89	V
$r_{\mathrm{T}}$	Forward Slope Resistance	$T_j=150$ °C				1.5	mΩ
$I_R$	Diode Reverse Current	$V_R = V_{RRM}$	$T_{j}=25^{\circ}C$ $T_{j}=150^{\circ}C$			0.1 20.0	mA
$V_{GT}$	Gate Trigger Current	$V_{\rm D} = 6V, T_{\rm i} = 25^{\rm o}$	С			1.5	V
$I_{GT}$	Gate Trigger Voltage	$V_{\rm D} = 6V_{\rm c}T_{\rm i} = 25^{\circ}{\rm C}$				95	mA
$V_{GD}$	Gate Non-trigger Current	$V_D = 0.67 V_{DRM}, T_j = 150^{\circ} C$				0.2	V
$I_{GD}$	Gate Non-trigger Voltage	$V_D = 0.67 V_{DRM}, T_j = 150^{\circ} C$				10	mA
$I_{\mathrm{H}}$	Holding Current	$V_{D} = 6V, R_{GK} = \infty, T_{i} = 25^{\circ}C$				200	mA
$I_{\rm L}$	Latching Current	t <sub>p</sub> =10μs,I <sub>G</sub> =0.45A, di <sub>G</sub> /dt=0.45A/μs,T <sub>i</sub> =25°C				450	mA
$t_{ m gd}$	Gate Controlled Delay Time	$I_G$ =0.5A,di <sub>G</sub> /dt=0.5A/ $\mu$ s, $T_i$ =25°C				2	μs
$t_{ m q}$	Circuit Commutated Turn-off Time	$V_R$ =100V, $V_D$ =0.67 $V_{DRM}$ , $I_T$ =165A, $t_p$ =200 $\mu$ s, $di/dt$ =10A/ $\mu$ s, $dv/dt$ =20V/ $\mu$ s, $T_j$ =125°C				185	μs

### Module Characteristics T<sub>C</sub>=25°C unless otherwise noted

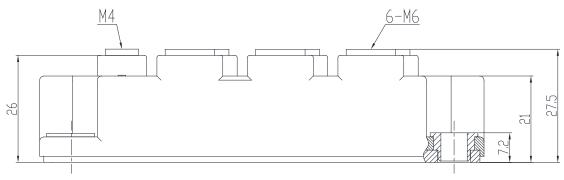
Symbol	Parameter	Min.	Тур.	Max.	Unit	
$R_{thJC}$	Junction-to-Case (per Rectifier)			0.352	K/W	
	Junction-to-Case (per Thyristor)			0.174	K/W	
	Case-to-Heatsink (per Rectifier)		0.297			
$R_{\text{thCH}}$	Case-to-Heatsink (per Thyristor)		0.147		K/W	
	Case-to-Heatsink (per Module)		0.037			
	Terminal Connection Torque, Screw M4		2.0			
M	Terminal Connection Torque, Screw M6		5.0		N.m	
	Mounting Torque, Screw M6		5.0			
G	Weight of Module		320		g	

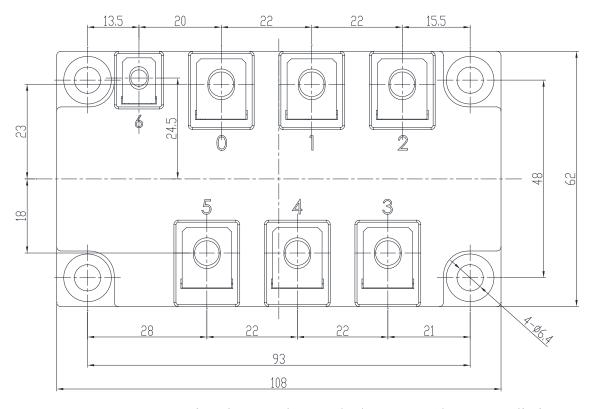
### **Circuit Schematic**



# **Package Dimensions**

#### Dimensions in Millimeters





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5/26/2015

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